

Supporting Information

Assembling Phosphorene Flexagons for 2D

Electron-density-guided Nanopatterning and Nanofabrication

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Brief computational setup

We perform first-principles density-functional theory (DFT) calculations with the projector-augmented wave (PAW) method as implemented in the Vienna *Ab initio* Simulation Package (VASP). In our DFT calculations, periodic boundary conditions are enforced with a vacuum region of 15 Å along the out-of-plane direction for all 2D models used in this work. A planewave kinetic energy cutoff of 500 eV is employed, and for geometry optimization, the semi-local approximation to the exchange-correlation functional due to Perdew, Burke, and Ernzerhof (PBE) is used. To achieve a higher precision in our electronic band structure calculations, we have adopted the HSE06 hybrid DFT functional instead. A Γ -centered \mathbf{k} -point grid of a reciprocal space sampling distance of 0.2 \AA^{-1} and 0.15 \AA^{-1} are used for all geometry optimization and electronic band structure calculations, respectively. All geometries are relaxed until the forces do not vary more than and 0.02 eV \AA^{-1} .

TABLE S1. The calculated elastic stiffness constants (in GPa) of selected phosphorene flexagons.

Structure	C_{11}	C_{12}	C_{22}	C_{44}	Born-Huang criteria
<i>he</i> -2F- <i>t</i>	17.10	-1.33	61.75	16.03	○
<i>he</i> -3F- <i>t</i>	27.08	12.25			○
<i>he</i> -4F- <i>t</i>	63.29	-7.42		5.74	○
<i>ho</i> -6F- <i>t</i>	27.71	18.51			○
α -P	24.31	17.48	103.95	22.65	○

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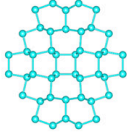
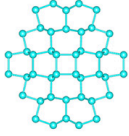


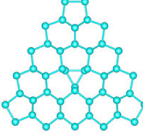
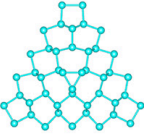
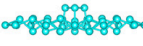

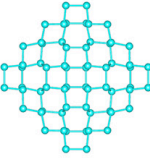
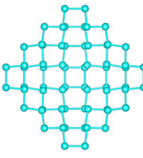
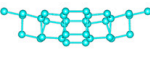
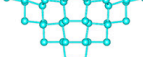
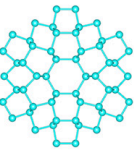
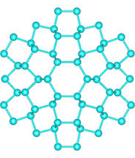
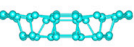
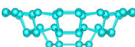
	Teller (<i>t</i>)	Schüssel (<i>s</i>)
2F		
		
3F		
		
4F		
		
6F		
		

FIG. S1. (Color online) Atomic structure of unit phosphorene nanoflakes with different symmetry (2-, 3-, 4-, and 6-fold) and shape (flat- (*t*) and bowl-shaped (*s*)), which used to build phosphorene flexagons.

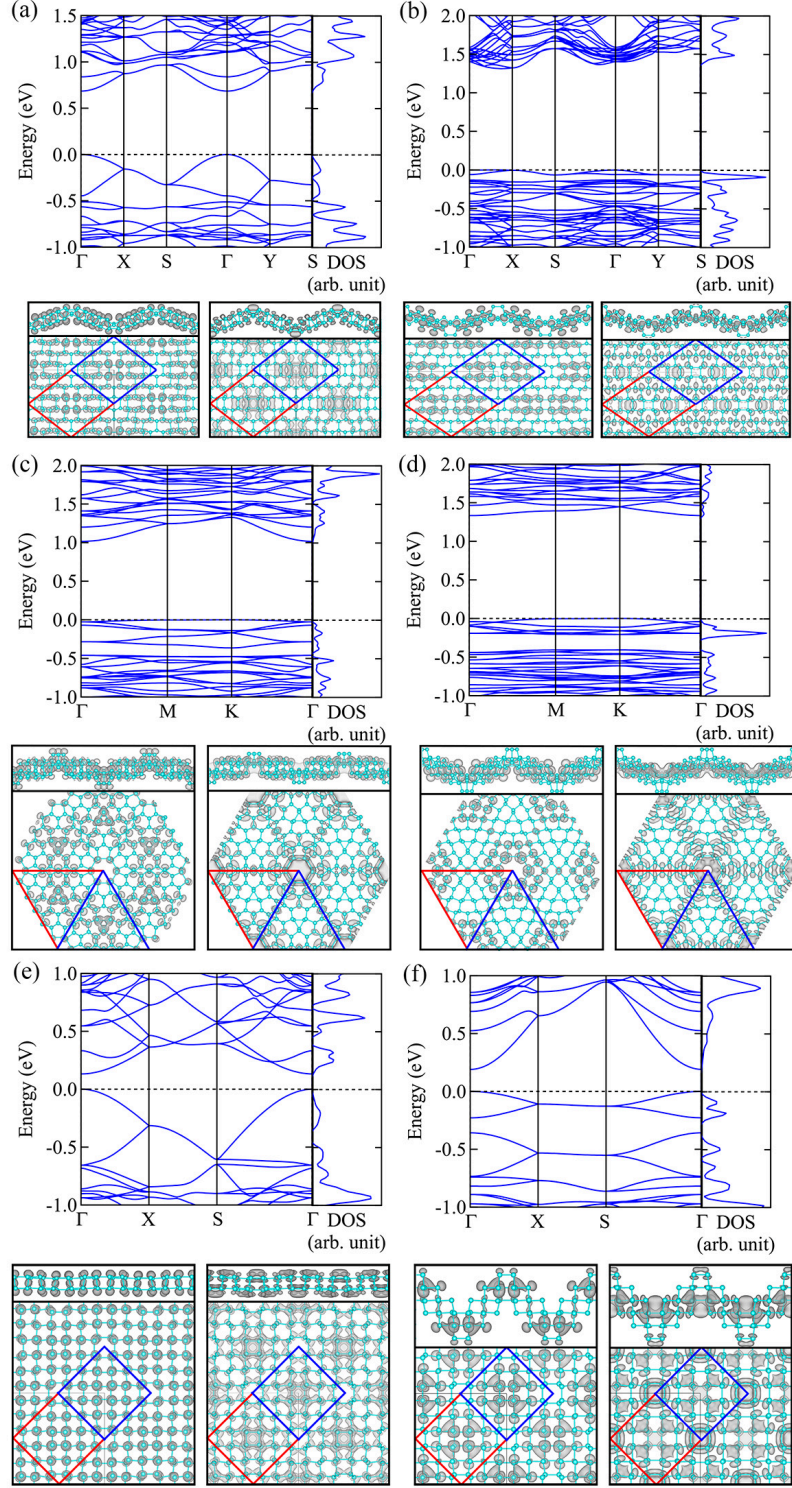


FIG. S2. (Color online) Calculated band structures, density-of-states, and partial electron densities at valence band edge (bottom-left) and conduction band edge (bottom-right) of *he*-flexagons; (a) *he*-2F-*t*, (b) *he*-2F-*s*, (c) *he*-3F-*t*, (d) *he*-3F-*s*, (e) *he*-4F-*t*, and (f) *he*-4F-*s*. Red and blue lines are to show different vertical arrangement of adjacent flakes.

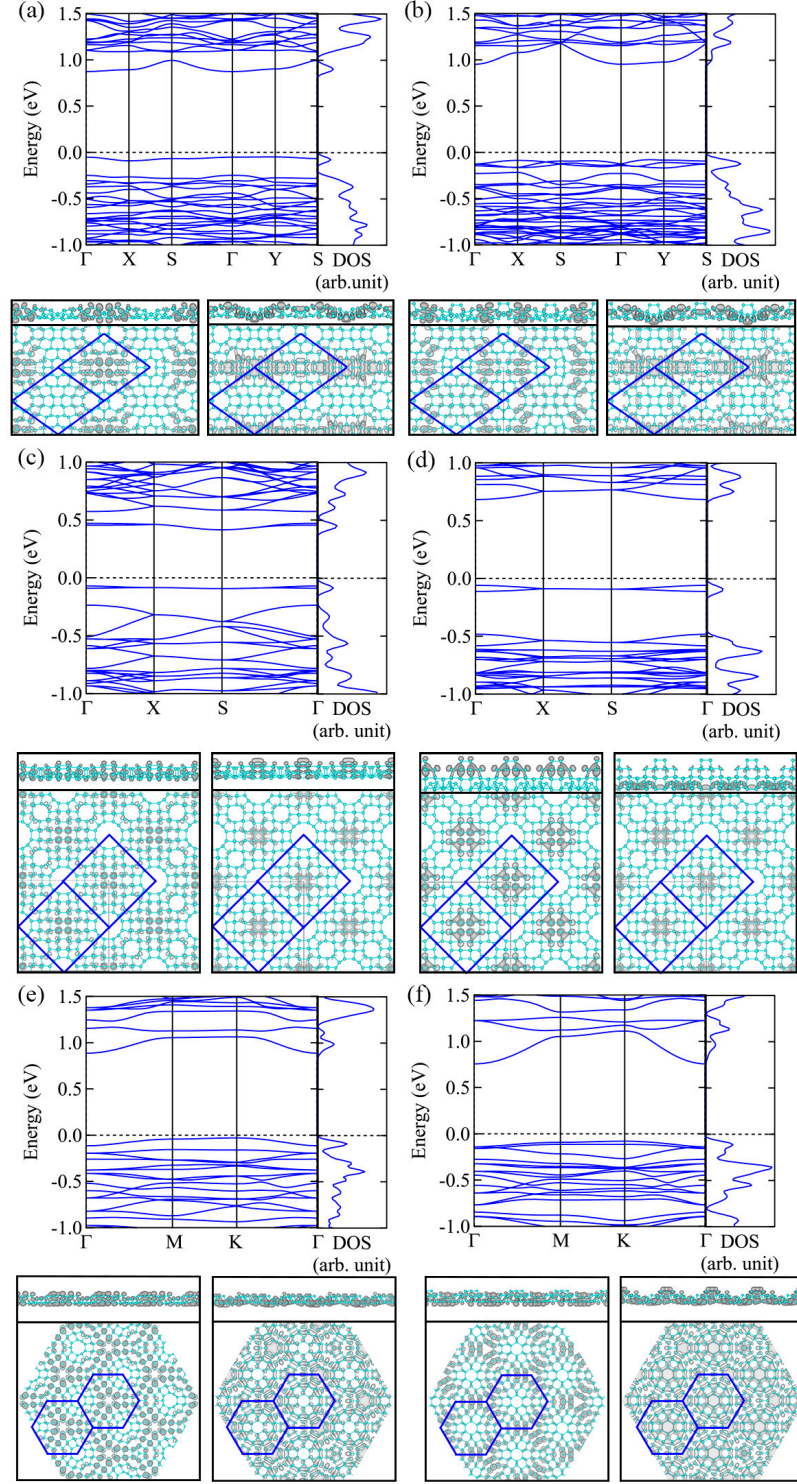
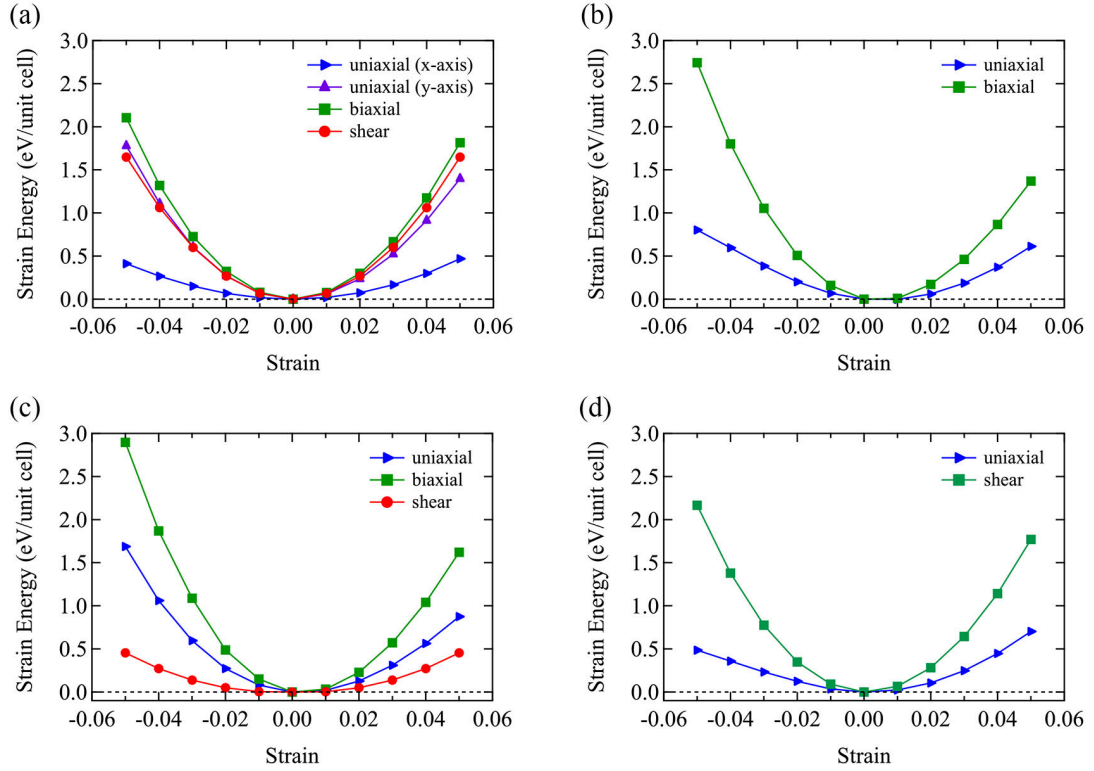
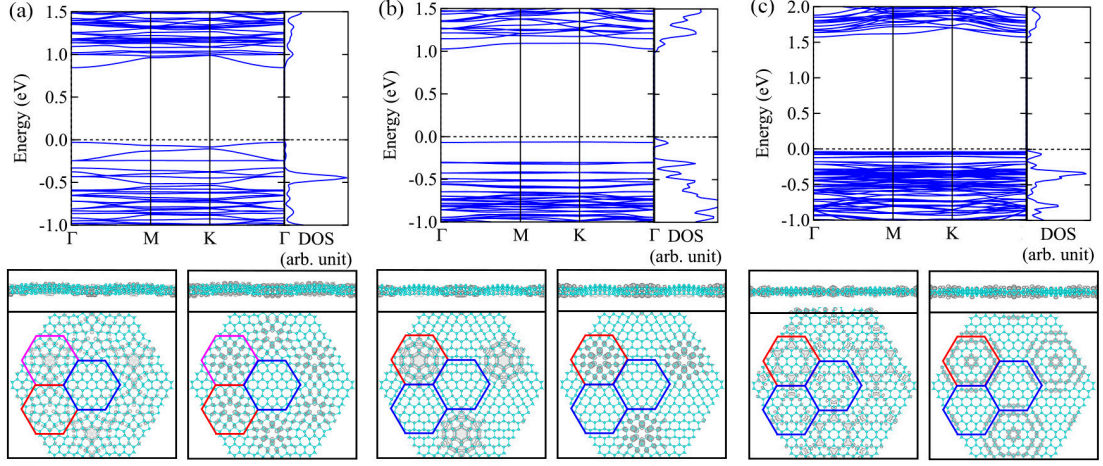


FIG. S3. (Color online) Calculated band structures, density-of-states, and partial electron densities at valence band edge (bottom-left) and conduction band edge (bottom-right) of *ho*-flexagons; (a) *ho*-2F-*t*, (b) *ho*-2F-*s*, (c) *ho*-4F-*t*, (d) *ho*-4F-*s*, (e) *ho*-6F-*t*, and (f) *ho*-6F-*s*. Blue lines are to show same vertical arrangement of adjacent flakes.



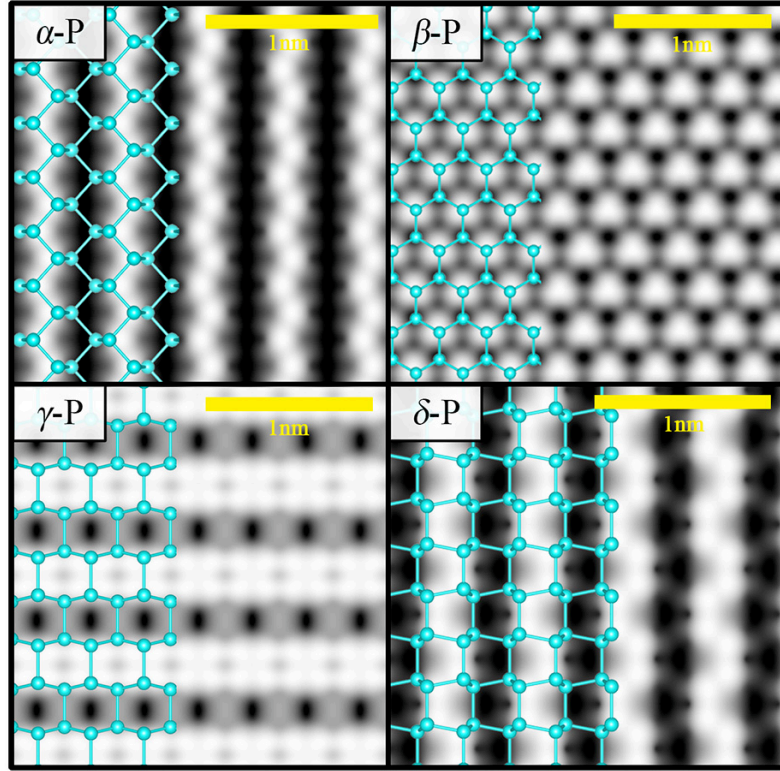


FIG. S6. (Color online) Simulated STM images and corresponding atomic positions of normal phosphorene phases; (a) α -, (b) β -, (c) γ -, and (d) δ -P.